

# Delocalization, thermal ionization, and energy transfer in singly doped and codoped $\text{CaAl}_4\text{O}_7$ and $\text{Y}_2\text{O}_3$

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$\text{Ce}^{3+}$  and  $\text{Tb}^{3+}$  singly doped and codoped  $\text{CaAl}_4\text{O}_7$  and  $\text{Y}_2\text{O}_3$  single crystal fibers were grown using the laser heated pedestal growth method. Energy transfer from  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$  was studied in these samples. No energy transfer between  $\text{Ce}^{3+}$  and  $\text{Tb}^{3+}$  was observed in codoped  $\text{Y}_2\text{O}_3$ . This is because electrons excited into the  $\text{Ce}^{3+}$   $5d$  states delocalize into the conduction band at a rate that is faster than the interionic energy transfer rate, whereas the converse is the case for  $\text{CaAl}_4\text{O}_7$  doped with  $\text{Ce}^{3+}$  (1 at %) and  $\text{Tb}^{3+}$  (1 at %). The energy transfer rate was determined to be on the order of  $10^9 \text{ s}^{-1}$ . The transfer occurs before the excited electrons can be thermally promoted into the conduction band. From these results, it can be inferred that the thermal ionization rate ( $W_{\text{Th}}$ ) from the lowest  $5d$  excited  $\text{Ce}^{3+}$  state at 355 nm is less than  $10^9 \text{ s}^{-1}$  at room temperature, whereas the delocalization rate ( $W_D$ ) into the conduction band is faster than this rate. The location of the  $\text{Tb}^{3+}$  and  $\text{Ce}^{3+}$  states relative to the valence and conduction band of these two materials has been determined through photoconductivity measurements.

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## I. INTRODUCTION

In practical applications, such as phosphors and solid-state lasers, rare earth ions are frequently used as doped activators.<sup>1–3</sup> The behavior of the active electrons of these ions in their excited state is important in determining the properties of the materials.

The spectra of the rare earth ions are dominated by intrastate,  $4f$  to  $4f$ , transitions which generally consist of sharp line spectra largely insensitive to the crystalline hosts. These properties are inherent to the nature of the  $4f$  states which are well shielded from external perturbations. Electrons in  $4f$  states are localized and can be designated to specific impurity ions.

The first set of interconfigurationally allowed states are the  $5d$  states, which are more extensive physically and hence interact more strongly with the surrounding ligands when in a solid. As a consequence, the  $4f$  to  $5d$  transitions are broad and can vary in energy considerably. The position of the  $5d$  states of rare earth ions has been extensively studied specially for  $\text{Ce}^{3+}$ .<sup>4</sup> Because of their extent,  $5d$  states are sensitive to crystalline field changes, and  $5d$  field components can be energy resonant with the conduction band of the host. Electrons promoted to  $5d$  states can become conduction electrons under the proper circumstances, resulting in the loss or delocalization of the electrons from the impurity ion. In other words, the impurity ion can be photoionized through  $5d$  excitation. Photoionization can be also thermally induced if optically excited states are below the conduction band but sufficiently close to it. If the state in question is emissive, thermal photoionization competes with the radiative process and affects the overall luminescence quantum efficiency of the state.<sup>5</sup>

Because of the simple energy level structure the  $(4f)^1$  configuration, the spectroscopic properties of  $\text{Ce}^{3+}$  in various hosts have been studied extensively.<sup>6</sup> Special emphasis has been placed on the nature of the  $5d$  states which are affected by the symmetry and strength of the crystalline field of the host matrix.<sup>7</sup> For cubic symmetry, the  $5d^1$  state will split into  $E$  and  $T$  states. For both  $\text{Y}_2\text{O}_3$  and  $\text{CaAl}_4\text{O}_7$  systems, the symmetries of  $\text{Y}^{3+}$  and  $\text{Ca}^{2+}$  sites are lower (the two  $\text{Y}^{3+}$  sites of symmetry  $C_2$  and  $C_{3i}$  and one  $\text{Ca}^{2+}$  site of symmetry  $C_2$ ),<sup>8,9</sup> causing further splitting of the  $E$  and  $T$  states. For  $\text{Y}_2\text{O}_3$ , the  $5d$  components fall within the conduction band, while in the case of  $\text{CaAl}_4\text{O}_7$  the lowest  $5d$  multiplet lies below the conduction band. The position of the lowest component of the  $5d$  states determines the radiative behavior of  $\text{Ce}^{3+}$  in a given material. For example, no  $5d$ - $4f$  luminescence is observed in  $\text{Y}_2\text{O}_3$ , while strong broadband transitions are observed in the Ca compound.<sup>10–12</sup> This is a consequence of the delocalization of the electron while in the conduction band.

$\text{Ce}^{3+}$  has been established as a luminescence sensitizer for the  $\text{Tb}^{3+}$  ion. The energy transfer process leading to the enhancement of the  $\text{Tb}^{3+}$   $4f$ - $4f$  transition originates from the metastable lowest  $5d$  state of the  $\text{Ce}^{3+}$  ion, and under the proper conditions, the energy transfer rate can be high enough to change the emission dynamics of the donor state. In the doubly doped system, interionic energy transfer provides an additional competing mechanism for the de-excitation of the  $\text{Ce}^{3+}$  state. The various mechanisms involved are schematically depicted in Fig. 1, including direct radiative decay back to the ground state, direct and thermally induced photoionization (delocalization), and the process of sensitization (energy transfer). Typically for rare earth systems, the radiative decay rate for a  $5d$  to  $4f$  transition ( $W_d$ ) is

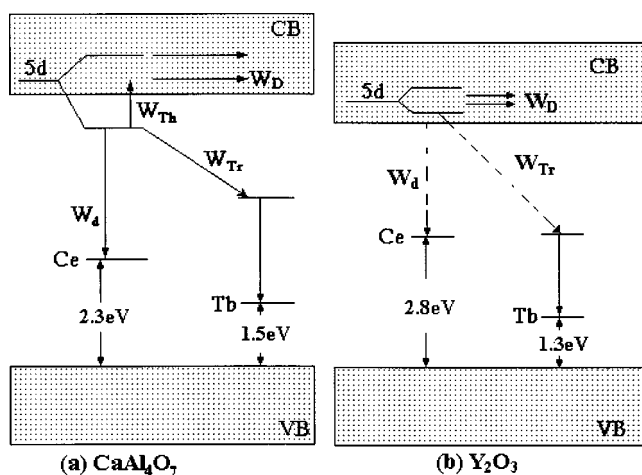


FIG. 1. Energy diagram of (a)  $\text{CaAl}_4\text{O}_7$ : $\text{Tb}^{3+}$ ,  $\text{Ce}^{3+}$  and (b)  $\text{Y}_2\text{O}_3$ : $\text{Tb}^{3+}$ ,  $\text{Ce}^{3+}$ .  $W_d$  is the decay rate of 355 nm 5d level of  $\text{Ce}^{3+}$ ,  $W_{Tr}$  the energy transfer rate from  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$ ,  $W_{Th}$  the thermal ionization rate, and  $W_D$  the delocalization rate (solid lines: occurred; dashed lines: did not occur).

of the order of  $10^7 \text{ s}^{-1}$ ; the energy transfer rate can be controlled by adjusting the concentrations of donor and acceptor, i.e., distance between the donors and acceptors.

In this work, by comparing the dynamic behavior of the  $\text{Ce}^{3+}$  excitation in the doubly doped systems and contrasting the competing de-excitations mechanisms for the 5d state, we find that we can make estimates for the thermal ionization rate ( $W_{Th}$ ) and the delocalization rate ( $W_D$ ) for rare earth electrons occupying the  $\text{Ce}^{3+}$  states. The thermal ionization rate ( $W_{Th}$ ) is analogous to the spin-lattice relaxation rate and is a measure of the strength of the electron-phonon interaction of the excited 5d states of rare earth ions with the host.

## II. EXPERIMENT

The  $\text{Y}_2\text{O}_3$ : $\text{Ce}^{3+}$ ,  $\text{Y}_2\text{O}_3$ : $\text{Tb}^{3+}$ ,  $\text{Y}_2\text{O}_3$ : $\text{Tb}^{3+}$ ,  $\text{Ce}^{3+}$ , and  $\text{CaAl}_4\text{O}_7$ : $\text{Ce}^{3+}$ ,  $\text{CaAl}_4\text{O}_7$ : $\text{Tb}^{3+}$ ,  $\text{CaAl}_4\text{O}_7$ : $\text{Tb}^{3+}$ ,  $\text{Ce}^{3+}$ , single crystal fibers were prepared by the laser heated pedestal growth (LHPG) method.<sup>13</sup> Pellets of the starting mixture were made with the proper mole ratio. The doping concentration is 1 at % for all dopants. The pellets were sintered at 1200 °C in air in a Linderburg blue tube furnace for 2 h and were cut and milled into 1-mm square rods with (without) a sharp tip to serve as the seed (feed). The samples were reduced at 1350 °C in a 5°  $\text{H}_2$ + $\text{N}_2$  gas flow. This is necessary because both  $\text{Ce}^{4+}$  and  $\text{Tb}^{4+}$  are also stable valence states. The fiber samples were polished into thin slabs (200–300  $\mu\text{m}$  thickness) along their fiber axis with two parallel end surfaces.

Photoconductivity spectra of the samples were measured at room temperature (290 K) and at 140 K. Ni meshes served as the electrodes. The light source was an Oriol 200 W Xenon lamp filtered through an ISA Jobin Yvon Spex monochromator. The samples were mounted in an electrically and thermally shielded vacuum cryostat. The applied voltage was about 10 000 V/cm. A Keithley 6517A elec-

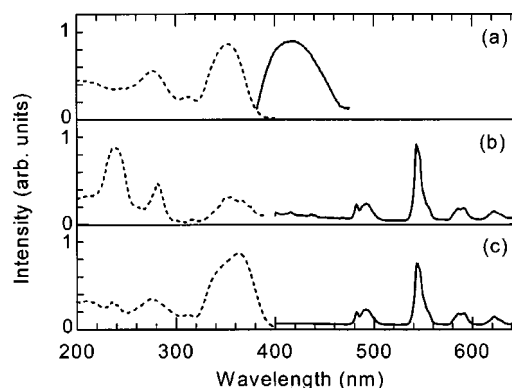


FIG. 2. Emission (solid lines) and excitation (dashed lines) spectra of the samples. All emissions are recorded upon excitation at 355 nm. The excitation spectra are monitored at 420, 542.9, and 542.9 nm for (a)  $\text{CaAl}_4\text{O}_7$ : $\text{Ce}^{3+}$ , (b)  $\text{CaAl}_4\text{O}_7$ : $\text{Tb}^{3+}$ , and (c)  $\text{CaAl}_4\text{O}_7$ : $\text{Tb}^{3+}$ ,  $\text{Ce}^{3+}$ , respectively.

trometer was used both as the high voltage supply and as the current detector.

The fluorescence lifetimes were recorded using a Tektronix 460A digital oscilloscope and a SPEX M500 spectrometer upon excitation with a frequency tripled Nd:YAG laser (pulse width  $\sim 7.0$  ns). The other optical measurements such as emission and excitation spectra were taken with a SPEX FluoroMax spectrofluorimeter. The band gaps of  $\text{Y}_2\text{O}_3$  and  $\text{CaAl}_4\text{O}_7$  are determined from the optical absorption to be 5.6 and 6.2 eV, respectively, using undoped samples.

## III. RESULTS AND DISCUSSION

### A. Energy transfer and thermal ionization in $\text{CaAl}_4\text{O}_7$ samples

Figure 2 shows the emission (solid) and excitation (dashed) spectra of the  $\text{CaAl}_4\text{O}_7$  samples doped with  $\text{Ce}^{3+}$  and  $\text{Tb}^{3+}$  individually [Figs. 2(a) and 2(b)] and jointly [Fig. 2(c)]. The doping concentration of the samples was nominally 1 at % for both dopant ions. The excitation spectra were obtained by monitoring emissions peaks for  $\text{Ce}^{3+}$  [420 nm, Fig. 2(a)] and  $\text{Tb}^{3+}$  [542.9 nm, Figs. 2(b) and 2(c)], respectively. The emission spectra were measured upon excitation at 355 nm corresponding to peak of the  $\text{Ce}^{3+}$  absorption.

For the singly  $\text{Ce}^{3+}$  doped samples, the excitation spectra consist of multiplets of the 5d state. The lowest 5d state peaking at 355 nm lies below the conduction band of  $\text{CaAl}_4\text{O}_7$ . The excitation spectra of  $\text{Tb}^{3+}$  consist of high lying 4f states as well as components of its 5d states.

The emission of  $\text{Ce}^{3+}$  in the codoped sample disappeared upon excitation at 355 nm, and the features of  $\text{Ce}^{3+}$  excitation appear in the excitation spectrum of  $\text{Tb}^{3+}$  when monitored at  $\text{Tb}^{3+}$  542.9-nm emission. These facts indicate that energy transfer from  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$  in the codoped sample takes place. The lifetime of the  $\text{Ce}^{3+}$  emission in the singly doped sample is measured to be 35 ns. In the codoped sample, it is greatly shortened and is not detectable by using an excitation pulse of 7 ns pulse width; this implies that the

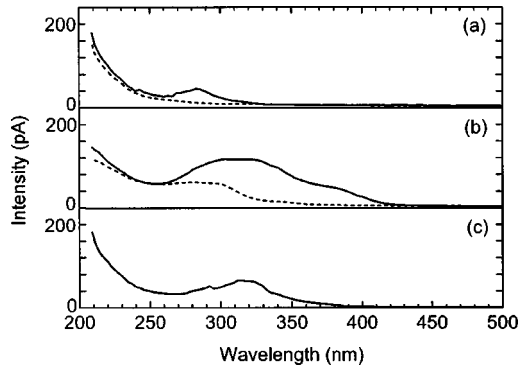


FIG. 3. Photoconductivity spectra of the  $\text{CaAl}_4\text{O}_7$  samples: (a)  $\text{CaAl}_4\text{O}_7:\text{Tb}^{3+}$ ; (b)  $\text{CaAl}_4\text{O}_7:\text{Ce}^{3+}$ ; (c)  $\text{CaAl}_4\text{O}_7:\text{Tb}^{3+}, \text{Ce}^{3+}$  (solid lines: 290 K; dashed lines: 140 K).

energy transfer rate,  $W_{Tr}$ , is  $\sim 10^9 \text{ s}^{-1}$  at 1 at % concentration and that is much faster than the  $\text{Ce}^{3+}$  emission rate,  $W_d$ , which is of the order of  $10^7 \text{ s}^{-1}$ . The energy transfer occurs from the lowest  $5d$  band of  $\text{Ce}^{3+}$  (at 355 nm). It depletes the population of lowest  $\text{Ce}^{3+}$  state rapidly and reduces the probability of thermal promotion to the conduction band. Details will be discussed in the section below.

Photoionization depends largely on the relative position of the impurity energy levels to the host band gap. Photoconductivity measurements are helpful in determining the impurity band positions relative to the host band gap, and in studying the thermal ionization of the excited state electrons. A photocurrent is observed as the electrons from impurities reach the conduction band. The photocurrent spectra are correlated to the excitation spectra of the electrons in the conduction band. If the excited states lie below the conduction band, then the photocurrent spectra will depend on the thermal ionization rate  $W_{Th}$  that is given in form of

$$W_{Th} = se^{-\Delta E/kT}, \quad (1)$$

where  $\Delta E$  is the energy difference between conduction band and the excited states below and  $s$  is a frequency factor, similar to that defined for thermal quenching.<sup>14</sup>

If thermal ionization is involved, the excitation spectra, and the photocurrent spectra will have some differences. The photocurrent of the excited states below the conduction band will be weaker than the excitation spectra, because fewer electrons are being promoted to the conduction band. The thermal dependence of the ionization process is such that at lower temperatures the onset of the photocurrent signal shifts to higher energies, and hence the energy splitting can be determined by using the two onset energies at two temperatures.

The photoconductivity spectra of the  $\text{Ce}^{3+}$  and  $\text{Tb}^{3+}$  singly- and codoped  $\text{CaAl}_4\text{O}_7$  samples are shown in Fig. 3.  $\text{Tb}^{3+}$  ions generate very weak photocurrent in the sample, as shown in Fig. 3(a). A photocurrent peak of  $\text{Tb}^{3+}$  is found at 283 nm and is assigned to the lowest  $5d$  states of  $\text{Tb}^{3+}$ . From the onsets at two temperatures (140 and 290 K) in Fig. 3 and assuming the photocurrent proportional to thermal ionization rate and emission intensity at the same wavelength, the energy difference between the conduction band and  $5d$  band at

283 nm for  $\text{Tb}^{3+}$  is estimated to be 0.33 eV. Taking the measured band gap value of  $\text{CaAl}_4\text{O}_7$  as 6.2 eV, the ground state of  $\text{Tb}^{3+}$  then can be placed 1.5 eV above the valence band, as shown in Fig. 1. No photocurrent signals were observed in the  $\text{Tb}^{3+} 4f-4f$  transition region.

The  $\text{Ce}^{3+}$  photocurrent spectra are shown in Fig. 3(b). At room temperature, the  $\text{Ce}^{3+}$  photocurrent spectrum agrees with the  $\text{Ce}^{3+}$  excitation spectrum. An interesting observation is that the photocurrent intensity is found to be weak while the excitation intensity is strong at 355 nm. A possible explanation is that thermal ionization occurs at the 355 nm ( $5d$  band), which means that the  $5d$  band of  $\text{Ce}^{3+}$  is below the host conduction band. In addition, the onset of the photocurrent spectrum shifts to higher energy at low temperature (140 K), also indicating that thermal ionization is occurring. The  $5d$  band at 355 nm is estimated to be  $\sim 0.3$  eV below the host conduction band calculated from the two onset energies at two temperatures. Hence, the  $\text{Ce}^{3+}$  ground state is about 2.3 eV above the host valence band (see Fig. 1). The positions of the other energy levels of the  $\text{Tb}^{3+}$  and  $\text{Ce}^{3+}$  relative to the host band gap can then be determined by these optical transition energies as determined by spectroscopy.

The photocurrent of the codoped sample is similar to the  $\text{Ce}^{3+}$  singly doped samples. The  $\text{Tb}^{3+}$  photocurrent is too weak to be detected in these samples. The photocurrent behavior at lower energies of the  $\text{Ce}^{3+} 5d$  level is very interesting; it is clearly much weaker than that of the singly doped sample. This indicates that energy transfer from  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$  is occurring and that the electron population at the  $5d$  state is being reduced quickly. Because of this, fewer electrons are available to be promoted to the conduction band through ionization. The thermal ionization rate  $W_{Th}$  of the electrons in the  $\text{Ce}^{3+} 5d$  band is slower than the energy transfer rate  $W_{Tr}$  ( $\sim 10^9 \text{ s}^{-1}$ ).

Based on the discussion above,  $W_{Th}$  can be estimated in between  $W_d$  ( $10^7 \text{ s}^{-1}$  or greater for singly doped  $\text{Ce}^{3+}$ ) and  $W_{Tr}$ . The frequency factor  $s$  can then be estimated to be of the order of  $10^{12} \text{ s}^{-1}$ , while the frequency factor of thermal detrapping process  $s_d$  in a similar host  $\text{CaAl}_2\text{O}_4$  has been found to be  $10^{8-9} \text{ s}^{-1}$ ,<sup>15,16</sup> which is very different from the  $s$  value in  $\text{CaAl}_4\text{O}_7$ .

### B. Energy transfer and delocalization in $\text{Y}_2\text{O}_3$

There is no  $\text{Ce}^{3+}$  emission is observed in  $\text{Y}_2\text{O}_3$ .<sup>10</sup> The  $\text{Tb}^{3+}$  excitation and emission spectra are shown in Fig. 4(a). The strong  $4f-5d$  transition of  $\text{Tb}^{3+}$  is found at 310 nm, while  $f-f$  transitions are observed at 492, 542.9, 590, and 630 nm, respectively.  $\text{Ce}^{3+}$  and  $\text{Tb}^{3+}$  were also codoped in  $\text{Y}_2\text{O}_3$ , and their emission and excitation spectra are shown in Fig. 4(b). The emission and excitation spectra of the  $\text{Tb}^{3+}$  singly doped and codoped with  $\text{Ce}^{3+}$  samples are identical and imply that there is no energy transfer from  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$  in this host. There is no absorption observed around 390 nm [that appears in the photocurrent spectrum in Fig. 5(c)] in the excitation spectrum when monitoring  $\text{Tb}^{3+}$  emission.

Photocurrent spectra of all three samples are shown in Fig. 5. The photocurrent of  $\text{Tb}^{3+} 5d$  states at 310 nm is quenched at low temperature because this state is below the

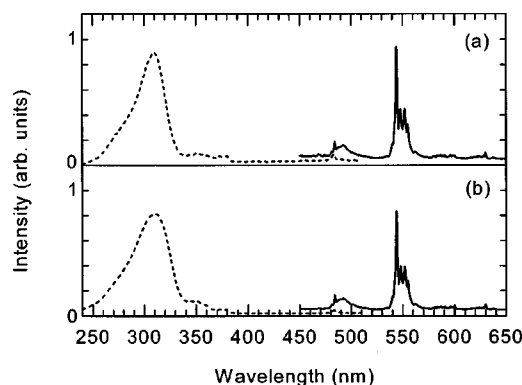


FIG. 4. Emission (solid lines) and excitation (dashed lines) spectra of the samples. Both emissions are recorded upon excitation at 310 nm and both excitation spectra are monitored at 542.9 nm. (a)  $\text{Y}_2\text{O}_3:\text{Tb}^{3+}$  and (b)  $\text{Y}_2\text{O}_3:\text{Tb}^{3+},\text{Ce}^{3+}$ .

conduction band. The onsets of photocurrent signals of  $\text{Tb}^{3+}$  are found at 324 nm (290 K) and 306 nm (140 K) as shown in Figs. 5(a) and 5(b). It follows that the  $5d$  band of  $\text{Tb}^{3+}$  at 310 nm is estimated 0.25 eV below the  $\text{Y}_2\text{O}_3$  conduction band. Using the measured band gap value of  $\text{Y}_2\text{O}_3$  as 5.6 eV, the ground state of  $\text{Tb}^{3+}$  can be placed at 1.3 eV above the  $\text{Y}_2\text{O}_3$  valence band. In the codoped sample, photocurrent peaks from both  $\text{Tb}^{3+}$  and  $\text{Ce}^{3+}$  are observed in Fig. 5(c) at room temperature. The  $\text{Ce}^{3+}$  photocurrent peak is found at 390 nm. The  $\text{Ce}^{3+}$   $5d$  bands are all in the conduction band, and its ground state is hence about 2.8 eV above the  $\text{Y}_2\text{O}_3$  valence band (see Fig. 1).

The  $\text{Ce}^{3+}$  emission is quenched by electron delocalization in  $\text{Y}_2\text{O}_3$  because all the  $5d$  bands are above the host conduction band. These delocalized electrons relax to the bottom of the conduction band. The  $\text{Ce}^{3+}$  emission rate  $W_d$  is normally  $10^7 \text{ s}^{-1}$ , so that the delocalization rate  $W_D$  in  $\text{Y}_2\text{O}_3$  must be faster than  $10^7 \text{ s}^{-1}$  in order to quench the  $\text{Ce}^{3+}$  emission.

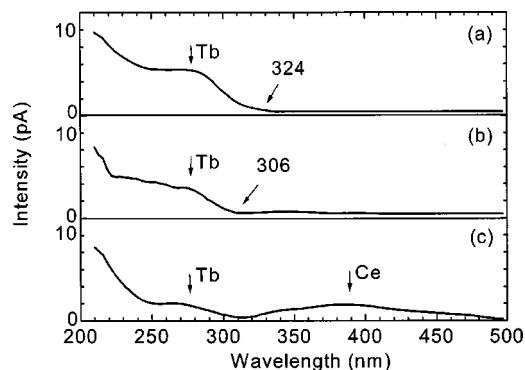


FIG. 5. Photoconductivity spectra: (a)  $\text{Y}_2\text{O}_3:\text{Tb}^{3+}$  at 290 K; (b)  $\text{Y}_2\text{O}_3:\text{Tb}^{3+}$  at 140 K; and (c)  $\text{Y}_2\text{O}_3:\text{Tb}^{3+},\text{Ce}^{3+}$  at 290 K.

In general, the energy transfer rate from  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$  is of the order of  $10^8$ – $10^9 \text{ s}^{-1}$ . The  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$  energy transfer is mostly due to a dipole-dipole interaction which depends on the donor-acceptor distance  $R$  ( $\propto 1/R^6$ ). Under the same doping concentration, the distance  $R$  between  $\text{Ce}^{3+}$  and  $\text{Tb}^{3+}$  is smaller in  $\text{Y}_2\text{O}_3$  than that in  $\text{CaAl}_4\text{O}_7$ , so that the energy transfer rate between  $\text{Ce}^{3+}$  and  $\text{Tb}^{3+}$  should be greater in  $\text{Y}_2\text{O}_3$  than in  $\text{CaAl}_4\text{O}_7$ ; the latter rate was estimated of the order of  $10^9 \text{ s}^{-1}$  at 1 at % doping concentration (it is far less than the quenching concentration).<sup>17</sup> The reason for the absence of energy transfer in  $\text{Y}_2\text{O}_3$  is that all the  $5d$  components are in the conduction band and the delocalization rate is much faster than the energy transfer rate, i.e.,  $W_D \gg W_{Tr}$  ( $\sim 10^9 \text{ s}^{-1}$ ). Once the electrons are excited to the  $5d$  states from the ground state, they delocalize to generate photocurrent, instead of engaging in the transfer of energy to  $\text{Tb}^{3+}$  to yield emission.

#### IV. CONCLUSION

We have studied two sets of samples,  $\text{CaAl}_4\text{O}_7:\text{Tb}^{3+}/\text{Ce}^{3+}/\text{Tb}^{3+},\text{Ce}^{3+}$  and  $\text{Y}_2\text{O}_3:\text{Tb}^{3+}/\text{Ce}^{3+}/\text{Tb}^{3+},\text{Ce}^{3+}$ . The energy transfer rate,  $W_{Tr}$ , from  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$  is of the order of  $10^9 \text{ s}^{-1}$  in both  $\text{CaAl}_4\text{O}_7$  and  $\text{Y}_2\text{O}_3$  systems. The  $\text{Tb}^{3+}$  and  $\text{Ce}^{3+}$  ground-state positions relative to hosts' band gap were determined by photoconductivity measurement. The  $\text{Tb}^{3+}$  ground state is 1.5 and 1.3 eV above the  $\text{CaAl}_4\text{O}_7$  and  $\text{Y}_2\text{O}_3$  valence band, respectively. The  $\text{Ce}^{3+}$  ground state is 2.3 and 2.8 eV above the  $\text{CaAl}_4\text{O}_7$  and  $\text{Y}_2\text{O}_3$  valence band, respectively.

The thermal ionization process of the  $\text{Ce}^{3+}$  ion is observed in  $\text{CaAl}_4\text{O}_7$ . A competition between thermal ionization and energy transfer is observed and allows us to estimate various rates. Thermal ionization of the  $5d$  electrons of  $\text{Ce}^{3+}$  at 355 nm is dominated by the energy transfer process from  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$  in  $\text{CaAl}_4\text{O}_7$ . The thermal ionization rate ( $W_{Th}$ ) at 355-nm  $5d$  level at 290 K in  $\text{CaAl}_4\text{O}_7$  is estimated in the range of  $W_{Tr}(\sim 10^9 \text{ s}^{-1}) > W_{Th} \sim W_d(\sim 10^7 \text{ s}^{-1})$ .

Delocalization of the  $5d$  electrons of  $\text{Ce}^{3+}$  ions in  $\text{Y}_2\text{O}_3$  is a dominant process in the de-excitation. The energy transfer from  $\text{Ce}^{3+}$  to  $\text{Tb}^{3+}$  is quenched by the delocalization of the  $5d$  electrons of  $\text{Ce}^{3+}$  in  $\text{Y}_2\text{O}_3$ . The delocalization, energy transfer, and radiation rates are found to have the following relationship:  $W_D > W_{Tr}(\sim 10^9 \text{ s}^{-1}) > W_d(\sim 10^7 \text{ s}^{-1})$ .

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